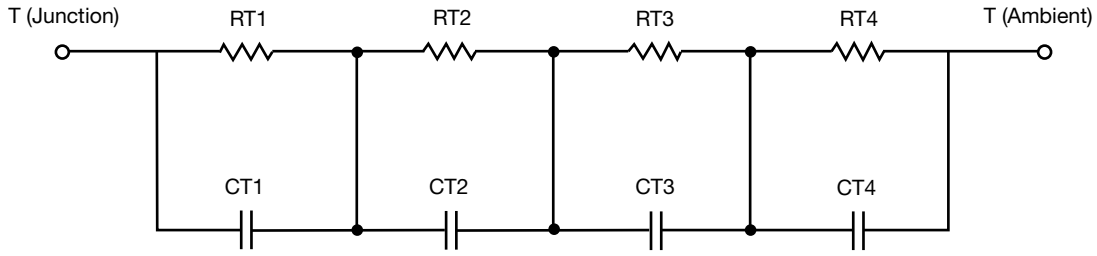
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, “Thermal Simulation of Power MOSFETs on the P-SPICE Platform”.

R-C THERMAL MODEL FOR TANK CONFIGURATION



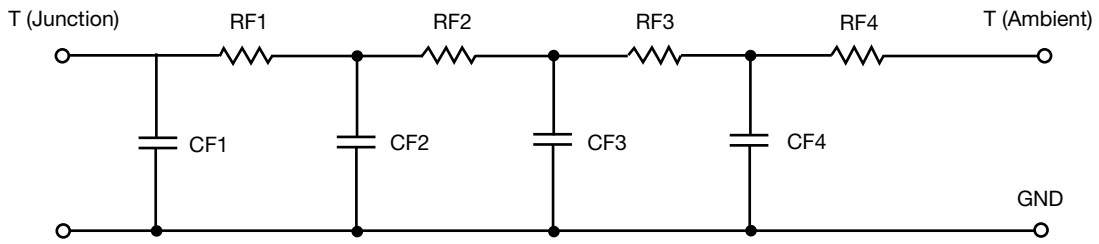
R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	**Ambient**	**Case**	**Foot**
RT1	13.1050	1.3523	N/A
RT2	27.0718	5.6589	N/A
RT3	26.9401	5.0019	N/A
RT4	42.8831	3.9869	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	**Ambient**	**Case**	**Foot**
CT1	96.2068u	1.0155m	N/A
CT2	2.0933m	564.8306u	N/A
CT3	34.5357m	55.9280u	N/A
CT4	1.1437	357.4204u	N/A

Note

- n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	**Ambient**	**Case**	**Foot**
RF1	14.4086	6.6789	N/A
RF2	28.3271	4.9199	N/A
RF3	25.9635	2.7079	N/A
RF4	41.3008	1.6933	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	**Ambient**	**Case**	**Foot**
CF1	98.5187u	37.0761u	N/A
CF2	1.8398m	118.4691u	N/A
CF3	33.4022m	211.8647u	N/A
CF4	1.1402	980.4259u	N/A

Note

- n/a indicates not applicable